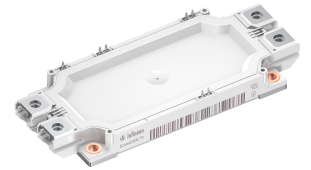


Final datasheet

EconoDUAL™3 module with Trench/Fieldstop IGBT4 and emitter controlled HE diode and PressFIT / NTC

Features

- Electrical features
 - $V_{CES} = 1200\text{ V}$
 - $I_{C\text{ nom}} = 450\text{ A} / I_{CRM} = 900\text{ A}$
 - Low $V_{CE,sat}$
 - $T_{vj,op} = 150^{\circ}\text{C}$
- Mechanical features
 - PressFIT contact technology
 - Standard housing



Potential applications

- Motor drives
- Servo drives
- UPS systems
- Wind turbines

Product validation

- Qualified for industrial applications according to the relevant tests of IEC 60747, 60749 and 60068

Description

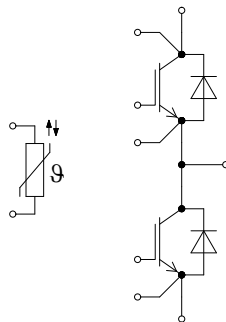


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1 Package

Table 1 Insulation coordination

Parameter	Symbol	Note or test condition	Values	Unit
Isolation test voltage	V_{ISOL}	RMS, $f = 50$ Hz, $t = 1$ min	2.5	kV
Isolation test voltage NTC	$V_{ISOL(NTC)}$	RMS, $f = 50$ Hz, $t = 1$ min	2.5	kV
Material of module baseplate			Cu	
Internal isolation		basic insulation (class 1, IEC 61140)	Al_2O_3	
Creepage distance	$d_{Creep\ nom}$	terminal to baseplate, nom., (PD2, IEC 60664-1, Ed. 3.0)	> 15	mm
Creepage distance	$d_{Creep\ min}$	terminal to baseplate, min., (PD2, IEC 60664-1, Ed. 3.0)	14.7	mm
Creepage distance	$d_{Creep\ nom}$	terminal to terminal, nom., (PD2, IEC 60664-1, Ed. 3.0)	12.1	mm
Creepage distance	$d_{Creep\ min}$	terminal to terminal, min., (PD2, IEC 60664-1, Ed. 3.0)	11.5	mm
Clearance	$d_{Clear\ nom}$	terminal to baseplate, nom.	> 12.5	mm
Clearance	$d_{Clear\ min}$	terminal to baseplate, min.	12.5	mm
Clearance	$d_{Clear\ nom}$	terminal to terminal, nom.	10.0	mm
Clearance	$d_{Clear\ min}$	terminal to terminal, min.	9.6	mm
Comparative tracking index	CTI		> 200	
Relative thermal index (electrical)	RTI	housing	140	°C

Table 2 Characteristic values

Parameter	Symbol	Note or test condition	Values			Unit
			Min.	Typ.	Max.	
Thermal resistance, case to heat sink	R_{thCH}	$\lambda_{grease} = 1$ W/(m·K)		0.009		K/W
Stray inductance module	L_{sCE}			20		nH
Module lead resistance, terminals - chip	$R_{CC'+EE'}$	$T_C = 25$ °C, per switch		1.1		mΩ
Storage temperature	T_{stg}		-40		125	°C
Mounting torque for module mounting	M	- Mounting according to valid application note		3	6	Nm
Terminal connection torque	M	- Mounting according to valid application note		3	6	Nm
Weight	G			345		g

2 IGBT, Inverter

Table 3 Maximum rated values

Parameter	Symbol	Note or test condition	Values	Unit
Collector-emitter voltage	V_{CES}	$T_{vj} = 25\text{ °C}$	1200	V
Continuous DC collector current	I_{CDC}	$T_{vj\ max} = 175\text{ °C}$ $T_C = 100\text{ °C}$	450	A
Repetitive peak collector current	I_{CRM}	t_p limited by $T_{vj\ op}$	900	A
Gate-emitter peak voltage	V_{GES}		± 20	V

Table 4 Characteristic values

Parameter	Symbol	Note or test condition	Values			Unit
			Min.	Typ.	Max.	
Collector-emitter saturation voltage	$V_{CE\ sat}$	$I_C = 450\text{ A}$, $V_{GE} = 15\text{ V}$	$T_{vj} = 25\text{ °C}$	1.75	2.10	V
			$T_{vj} = 125\text{ °C}$	2.00		
			$T_{vj} = 150\text{ °C}$	2.05		
Gate threshold voltage	V_{GETh}	$I_C = 17.1\text{ mA}$, $V_{CE} = V_{GE}$, $T_{vj} = 25\text{ °C}$	5.20	5.80	6.40	V
Gate charge	Q_G	$V_{GE} = \pm 15\text{ V}$		3.3		μC
Internal gate resistor	R_{Gint}	$T_{vj} = 25\text{ °C}$		1.7		Ω
Input capacitance	C_{ies}	$f = 1000\text{ kHz}$, $T_{vj} = 25\text{ °C}$, $V_{CE} = 25\text{ V}$, $V_{GE} = 0\text{ V}$		28		nF
Reverse transfer capacitance	C_{res}	$f = 1000\text{ kHz}$, $T_{vj} = 25\text{ °C}$, $V_{CE} = 25\text{ V}$, $V_{GE} = 0\text{ V}$		1.55		nF
Collector-emitter cut-off current	I_{CES}	$V_{CE} = 1200\text{ V}$, $V_{GE} = 0\text{ V}$ $T_{vj} = 25\text{ °C}$			3	mA
Gate-emitter leakage current	I_{GES}	$V_{CE} = 0\text{ V}$, $V_{GE} = 20\text{ V}$, $T_{vj} = 25\text{ °C}$			400	nA
Turn-on delay time (inductive load)	t_{don}	$I_C = 450\text{ A}$, $V_{CC} = 600\text{ V}$, $V_{GE} = \pm 15\text{ V}$, $R_{Gon} = 1.3\ \Omega$	$T_{vj} = 25\text{ °C}$	0.190		μs
			$T_{vj} = 125\text{ °C}$	0.220		
			$T_{vj} = 150\text{ °C}$	0.220		
Rise time (inductive load)	t_r	$I_C = 450\text{ A}$, $V_{CC} = 600\text{ V}$, $V_{GE} = \pm 15\text{ V}$, $R_{Gon} = 1.3\ \Omega$	$T_{vj} = 25\text{ °C}$	0.060		μs
			$T_{vj} = 125\text{ °C}$	0.070		
			$T_{vj} = 150\text{ °C}$	0.070		
Turn-off delay time (inductive load)	t_{doff}	$I_C = 450\text{ A}$, $V_{CC} = 600\text{ V}$, $V_{GE} = \pm 15\text{ V}$, $R_{Goff} = 1.3\ \Omega$	$T_{vj} = 25\text{ °C}$	0.490		μs
			$T_{vj} = 125\text{ °C}$	0.580		
			$T_{vj} = 150\text{ °C}$	0.620		

(table continues...)

Table 4 (continued) Characteristic values

Parameter	Symbol	Note or test condition	Values			Unit
			Min.	Typ.	Max.	
Fall time (inductive load)	t_f	$I_C = 450 \text{ A}, V_{CC} = 600 \text{ V}, V_{GE} = \pm 15 \text{ V}, R_{Goff} = 1.3 \Omega$	$T_{vj} = 25 \text{ }^\circ\text{C}$	0.080		μs
			$T_{vj} = 125 \text{ }^\circ\text{C}$	0.110		
			$T_{vj} = 150 \text{ }^\circ\text{C}$	0.120		
Turn-on energy loss per pulse	E_{on}	$I_C = 450 \text{ A}, V_{CC} = 600 \text{ V}, L_\sigma = 35 \text{ nH}, V_{GE} = \pm 15 \text{ V}, R_{Gon} = 1.3 \Omega, di/dt = 7000 \text{ A}/\mu\text{s} (T_{vj} = 150 \text{ }^\circ\text{C})$	$T_{vj} = 25 \text{ }^\circ\text{C}$	15		mJ
			$T_{vj} = 125 \text{ }^\circ\text{C}$	26		
			$T_{vj} = 150 \text{ }^\circ\text{C}$	28.5		
Turn-off energy loss per pulse	E_{off}	$I_C = 450 \text{ A}, V_{CC} = 600 \text{ V}, L_\sigma = 35 \text{ nH}, V_{GE} = \pm 15 \text{ V}, R_{Goff} = 1.3 \Omega, dv/dt = 3100 \text{ V}/\mu\text{s} (T_{vj} = 150 \text{ }^\circ\text{C})$	$T_{vj} = 25 \text{ }^\circ\text{C}$	38		mJ
			$T_{vj} = 125 \text{ }^\circ\text{C}$	55.5		
			$T_{vj} = 150 \text{ }^\circ\text{C}$	61.5		
SC data	I_{SC}	$V_{GE} \leq 15 \text{ V}, V_{CC} = 800 \text{ V}, V_{CEmax} = V_{CES} - L_{SCE} \cdot di/dt$	$t_p \leq 10 \mu\text{s}, T_{vj} = 150 \text{ }^\circ\text{C}$	1800		A
Thermal resistance, junction to case	R_{thJC}	per IGBT			0.0660	K/W
Thermal resistance, case to heat sink	R_{thCH}	per IGBT, $\lambda_{grease} = 1 \text{ W}/(\text{m}\cdot\text{K})$		0.0300		K/W
Temperature under switching conditions	$T_{vj op}$		-40		150	$^\circ\text{C}$

3 Diode, Inverter

Table 5 Maximum rated values

Parameter	Symbol	Note or test condition	Values	Unit	
Repetitive peak reverse voltage	V_{RRM}	$T_{vj} = 25 \text{ }^\circ\text{C}$	1200	V	
Continuous DC forward current	I_F		450	A	
Repetitive peak forward current	I_{FRM}	$t_p = 1 \text{ ms}$	900	A	
I^2t - value	I^2t	$t_p = 10 \text{ ms}, V_R = 0 \text{ V}$	$T_{vj} = 125 \text{ }^\circ\text{C}$	35000	A^2s
			$T_{vj} = 150 \text{ }^\circ\text{C}$	28500	

Table 6 Characteristic values

Parameter	Symbol	Note or test condition	Values			Unit	
			Min.	Typ.	Max.		
Forward voltage	V_F	$I_F = 450 \text{ A}, V_{GE} = 0 \text{ V}$	$T_{vj} = 25 \text{ °C}$		1.65	2.10	V
			$T_{vj} = 125 \text{ °C}$		1.65		
			$T_{vj} = 150 \text{ °C}$		1.65		
Peak reverse recovery current	I_{RM}	$V_{CC} = 600 \text{ V}, I_F = 450 \text{ A}, V_{GE} = -15 \text{ V}, -di_F/dt = 7000 \text{ A}/\mu\text{s} (T_{vj} = 150 \text{ °C})$	$T_{vj} = 25 \text{ °C}$		450		A
			$T_{vj} = 125 \text{ °C}$		550		
			$T_{vj} = 150 \text{ °C}$		575		
Recovered charge	Q_r	$V_{CC} = 600 \text{ V}, I_F = 450 \text{ A}, V_{GE} = -15 \text{ V}, -di_F/dt = 7000 \text{ A}/\mu\text{s} (T_{vj} = 150 \text{ °C})$	$T_{vj} = 25 \text{ °C}$		48		μC
			$T_{vj} = 125 \text{ °C}$		92		
			$T_{vj} = 150 \text{ °C}$		105		
Reverse recovery energy	E_{rec}	$V_{CC} = 600 \text{ V}, I_F = 450 \text{ A}, V_{GE} = -15 \text{ V}, -di_F/dt = 7000 \text{ A}/\mu\text{s} (T_{vj} = 150 \text{ °C})$	$T_{vj} = 25 \text{ °C}$		26.5		mJ
			$T_{vj} = 125 \text{ °C}$		48.5		
			$T_{vj} = 150 \text{ °C}$		55		
Thermal resistance, junction to case	R_{thJC}	per diode				0.100	K/W
Thermal resistance, case to heat sink	R_{thCH}	per diode, $\lambda_{grease} = 1 \text{ W}/(\text{m}\cdot\text{K})$			0.0450		K/W
Temperature under switching conditions	$T_{vj\text{op}}$			-40		150	°C

4 NTC-Thermistor

Table 7 Characteristic values

Parameter	Symbol	Note or test condition	Values			Unit
			Min.	Typ.	Max.	
Rated resistance	R_{25}	$T_{NTC} = 25 \text{ °C}$		5		k Ω
Deviation of R_{100}	$\Delta R/R$	$T_{NTC} = 100 \text{ °C}, R_{100} = 493 \text{ }\Omega$	-5		5	%
Power dissipation	P_{25}	$T_{NTC} = 25 \text{ °C}$			20	mW
B-value	$B_{25/50}$	$R_2 = R_{25} \exp[B_{25/50}(1/T_2 - 1/(298,15 \text{ K}))]$		3375		K
B-value	$B_{25/80}$	$R_2 = R_{25} \exp[B_{25/80}(1/T_2 - 1/(298,15 \text{ K}))]$		3411		K
B-value	$B_{25/100}$	$R_2 = R_{25} \exp[B_{25/100}(1/T_2 - 1/(298,15 \text{ K}))]$		3433		K

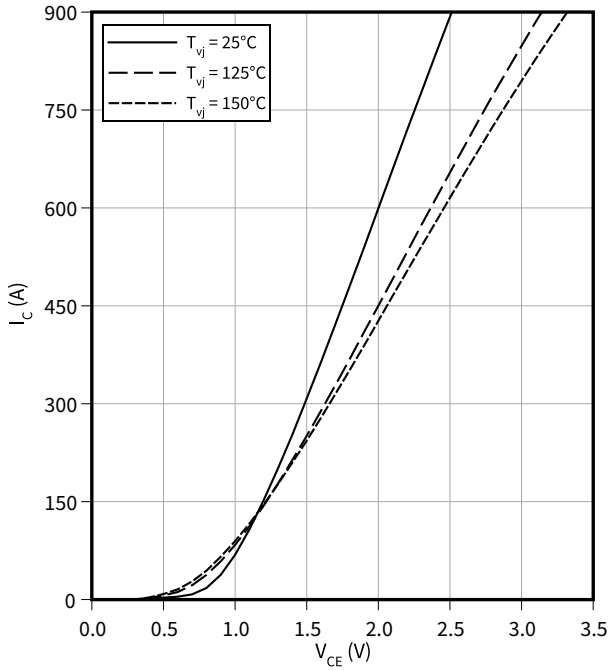
Note: For an analytical description of the NTC characteristics please refer to AN2009-10, chapter 4

5 Characteristics diagrams

Output characteristic (typical), IGBT, Inverter

$$I_C = f(V_{CE})$$

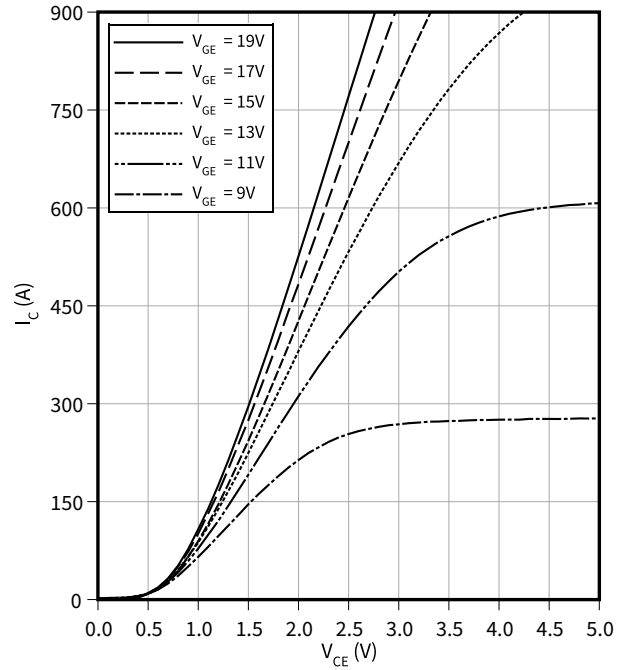
$$V_{GE} = 15 \text{ V}$$



Output characteristic field (typical), IGBT, Inverter

$$I_C = f(V_{CE})$$

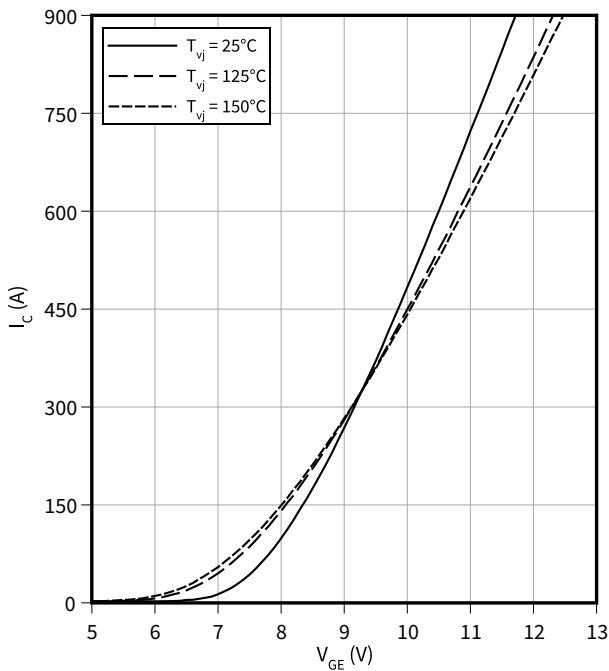
$$T_{vj} = 150 \text{ °C}$$



Transfer characteristic (typical), IGBT, Inverter

$$I_C = f(V_{GE})$$

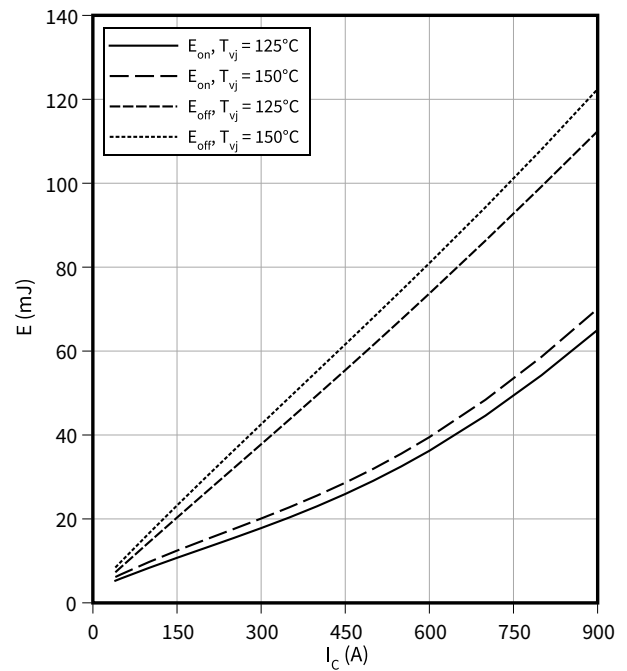
$$V_{CE} = 20 \text{ V}$$



Switching losses (typical), IGBT, Inverter

$$E = f(I_C)$$

$$R_{Gon} = 1.3 \text{ } \Omega, V_{GE} = -15 / 15 \text{ V}, V_{CC} = 600 \text{ V}, R_{Goff} = 1.3 \text{ } \Omega$$

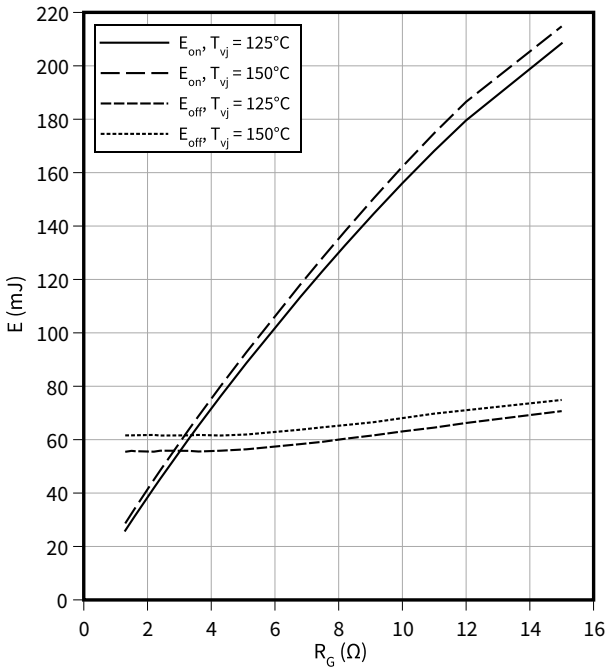


5 Characteristics diagrams

Switching losses (typical), IGBT, Inverter

$E = f(R_G)$

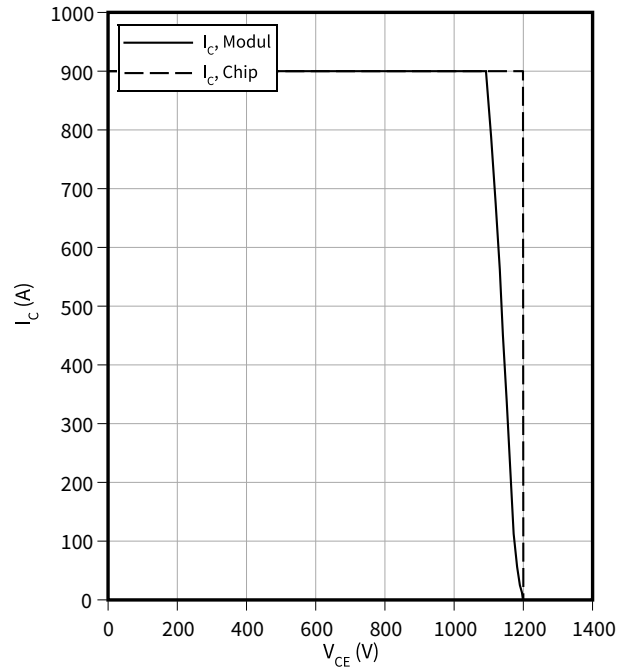
$V_{GE} = -15 / 15 \text{ V}, V_{CC} = 600 \text{ V}, I_C = 450 \text{ A}$



Reverse bias safe operating area (RBSOA), IGBT, Inverter

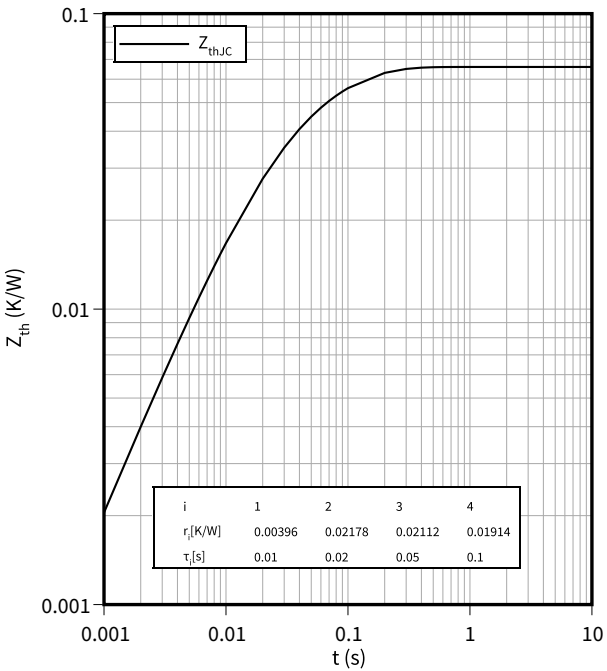
$I_C = f(V_{CE})$

$R_{Goff} = 1.3 \Omega, V_{GE} = \pm 15 \text{ V}, T_{vj} = 150 \text{ °C}$



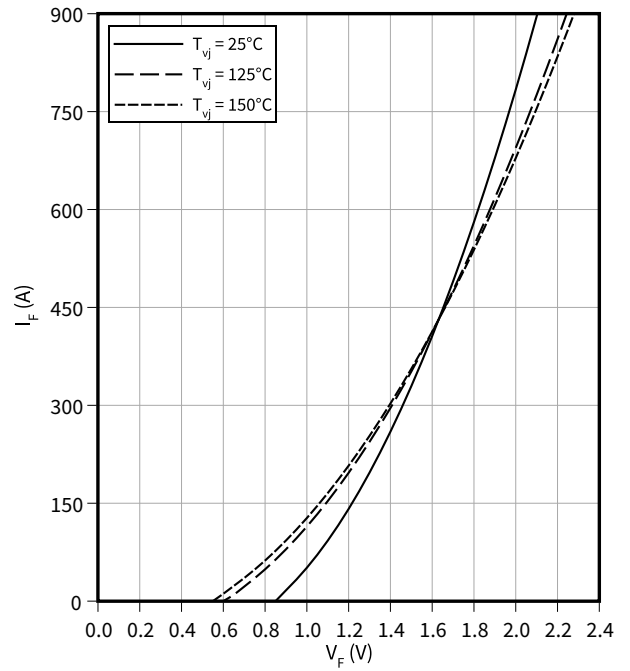
Transient thermal impedance, IGBT, Inverter

$Z_{th} = f(t)$



Forward characteristic (typical), Diode, Inverter

$I_F = f(V_F)$

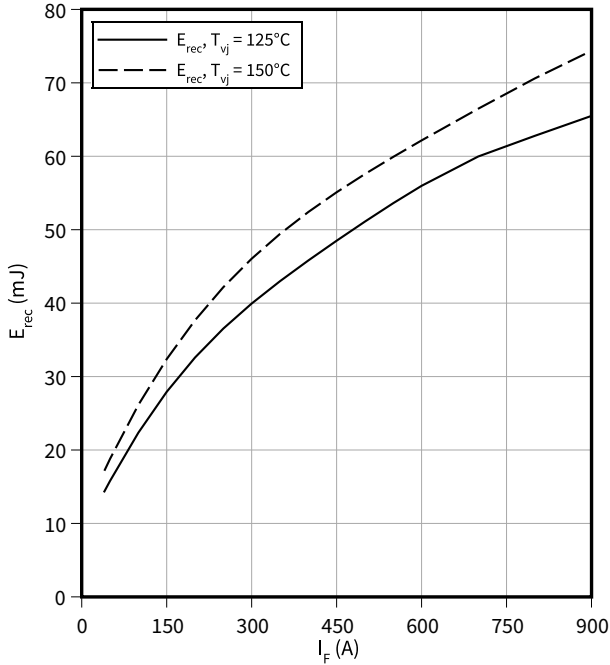


5 Characteristics diagrams

Switching losses (typical), Diode, Inverter

$E_{rec} = f(I_F)$

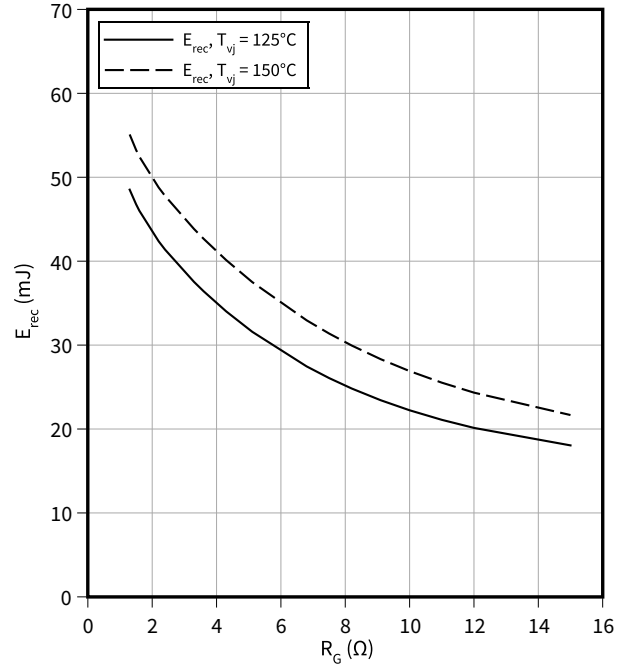
$R_{Gon} = R_{Gon}(IGBT), V_{CC} = 600 V$



Switching losses (typical), Diode, Inverter

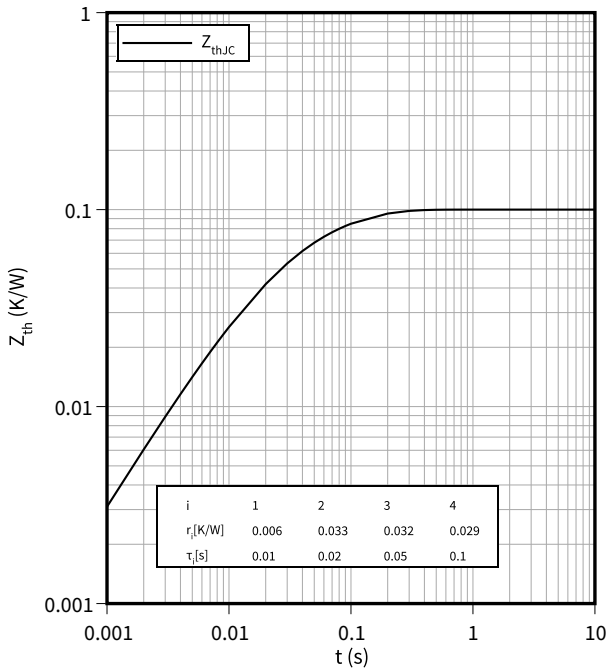
$E_{rec} = f(R_G)$

$I_F = 450 A, V_{CC} = 600 V$



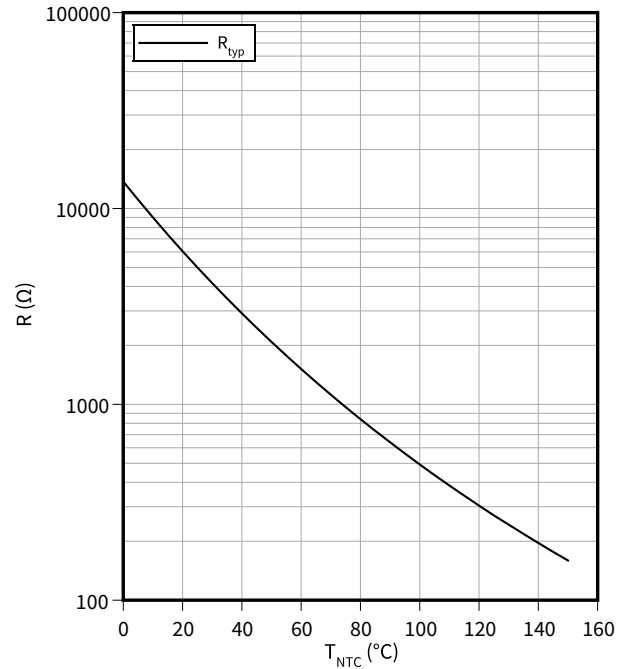
Transient thermal impedance, Diode, Inverter

$Z_{th} = f(t)$



Temperature characteristic (typical), NTC-Thermistor

$R = f(T_{NTC})$



8 Module label code


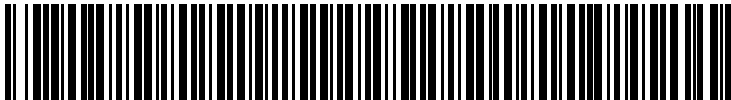
Module label code			
Code format	Data Matrix	Barcode Code128	
Encoding	ASCII text	Code Set A	
Symbol size	16x16	23 digits	
Standard	IEC24720 and IEC16022	IEC8859-1	
Code content	Content	Digit	Example
	Module serial number	1 - 5	71549
	Module material number	6 - 11	142846
	Production order number	12 - 19	55054991
	Date code (production year)	20 - 21	15
	Date code (production week)	22 - 23	30
Example	 		
	71549142846550549911530		71549142846550549911530

Figure 3

Revision history

Document revision	Date of release	Description of changes
V2.0	2011-04-26	Preliminary datasheet
n/a	2020-09-01	Datasheet migrated to a new system with a new layout and new revision number schema: target or preliminary datasheet = 0.xy; final datasheet = 1.xy
1.00	2024-03-18	Final datasheet

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[FP06R12W1T4_B3](#) [FP100R07N3E4](#) [FP100R07N3E4_B11](#) [FP10R06W1E3_B11](#) [FP10R12W1T4_B11](#) [FP10R12YT3](#) [FP15R12W2T4](#)
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[FS150R17N3E4_B11](#) [FS20R06W1E3_B11](#) [FS30R06W1E3_B11](#) [FS75R12KE3G](#) [FS75R12W2T4_B11](#) [FZ1600R17HP4_B2](#)
[FZ300R12KE3G](#) [FZ400R17KE3](#) [FZ400R17KE4](#) [FZ600R65KE3](#) [DF1000R17IE4D_B2](#) [APTGT75DA60T1G](#) [DZ800S17K3](#) [F12-](#)
[25R12KT4G](#) [F3L200R12W2H3_B11](#) [F3L300R12ME4_B22](#) [F3L75R07W2E3_B11](#) [F4-150R12KS4](#) [F475R07W1H3B11ABOMA1](#)
[FD1400R12IP4D](#) [FD400R12KE3_B5](#)